

Product data sheet COMPANY PUBLIC

## **1** General description

The BGU8051 is, also known as the BTS1001L, a low noise high linearity amplifier for wireless infrastructure applications, equipped with fast shutdown to support TDD systems. The LNA has a high input and output return loss and is designed to operate between 0.3 GHz and 1.5 GHz. It is housed in a 2 mm × 2 mm × 0.75 mm 8-terminal plastic thin small outline package. The LNA is ESD protected on all terminals.

## 2 Features and benefits

- Low noise performance: NF = 0.43 dB
- High linearity performance: IP3<sub>O</sub> = 39 dBm
- High input return loss > 15 dB
- High output return loss > 20 dB
- · Unconditionally stable
- Programmable bias current (via resistor)
- Small 8-terminal leadless package 2 mm × 2 mm × 0.75 mm
- · ESD protection on all terminals
- · Moisture sensitivity level 1
- · Fast shut down to support TDD systems
- 3 V to 5 V single supply

## 3 Applications

- Wireless infrastructure
- · Low noise and high linearity applications
- LTE, W-CDMA, CDMA, GSM
- · General-purpose wireless applications
- TDD or FDD systems
- · Suitable for small cells



# 4 Quick reference data

#### Table 1. Quick reference data

f = 900 MHz,  $V_{CC} = 5 \text{ V}$ ,  $T_{amb} = 25 \text{ °C}$ , input and output 50  $\Omega$ ;  $R_{bias} = 5.1 \text{ k}\Omega$ ; unless otherwise specified. All RF parameters are measured in an application board as shown in Figure <u>16</u> with components listed in <u>Table 9</u> optimized for f = 900 MHz.

Symbol	Parameter	Conditions	Min	Тур	Max	Unit
I <sub>CC</sub>	supply current	on state	36	48	60	mA
		off state	-	2.8	-	mA
G <sub>ass</sub>	associated gain	on state	17	18.3	20	dB
		off state	-	-21	-	dB
NF	noise figure		-	0.43	0.63	dB
P <sub>L(1dB)</sub>	output power at 1 dB gain compression		-	19	-	dBm
IP3 <sub>0</sub>	output third-order intercept point	2-tone; tone spacing = 1 MHz;P <sub>i</sub> = -15 dBm per tone	35	39	-	dBm

# **5** Ordering information

#### Table 2. Ordering information

Type number	Package		
	Name	Description	Version
BGU8051	HWSON8	plastic thermal enhanced very very thin small outline package; no leads; 8 terminals; body 2 × 2 × 0.75 mm	SOT1327-1

## 6 Block diagram



# 7 Pinning information

## 7.1 Pinning



## 7.2 Pin description

Table 3. Pin description					
Symbol	Pin	Description			
V <sub>BIAS</sub>	1	bias voltage			
RF_IN	2	RF input			
n.c.	3, 8	not connected			
i.c.	4, 5	internally connected. Can be grounded or left open in the application			
SHDN	6	shutdown			
RF_OUT	7	RF output			
GND	exposed die pad	ground			

#### **Limiting values** 8

#### Table 4. Limiting values

In accordance with the Absolute Maximum Rating System (IEC 60134).

Symbol	Parameter	Conditions	Min	Мах	Unit
V <sub>CC</sub>	supply voltage		-	6	V
V <sub>ctrl(sd)</sub>	shutdown control voltage		-	3	V
I <sub>CC</sub>	supply current		-	85	mA
P <sub>i(RF)CW</sub>	continuous waveform RF input power		-	20	dBm
T <sub>stg</sub>	storage temperature		-40	+150	°C
Тj	junction temperature		-	150	°C
Р	power dissipation	$T_{case} \le 125 \ ^{\circ}C$ [1]	-	510	mW
V <sub>ESD</sub>	electrostatic discharge voltage	Human Body Model (HBM) According to ANSI/ESDA/JEDEC standard JS-001-2010	-	1.5	kV
		Charged Device Model (CDM); According to JEDEC standard 22-C101B	-	2	kV

Case is ground solder pad. [1]

#### **Recommended operating conditions** 9

#### Table 5. Recommended operating conditions

Symbol	Parameter	Conditions	Min	Тур	Мах	Unit
V <sub>CC</sub>	supply voltage		3.3	5	5.25	V
Z <sub>0</sub>	characteristic impedance		-	50	-	Ω
T <sub>case</sub>	case temperature		-40	-	+85	°C

## **10 Thermal characteristics**

#### Table 6. Thermal characteristics

Symbol	Parameter	Conditions	Тур	Unit
R <sub>th(j-case)</sub>	thermal resistance from junction to case	[1] [2	<sup>]</sup> 50	K/W

[1]

Case is ground solder pad. Thermal resistance measured using infrared measurement technique, device mounted on application board and placed in still air. [2]

## **11 Characteristics**

#### Table 7. Characteristics

f = 900 MHz,  $V_{CC} = 5 \text{ V}$ ,  $T_{amb} = 25 \text{ °C}$ , input and output 50  $\Omega$ ;  $R_{bias} = 5.1 \text{ k}\Omega$ ; unless otherwise specified. All RF parameters are measured in an application board as shown in Figure 16 with components listed in Table 9 optimized for f = 900 MHz.

Symbol	Parameter	Conditions	Min	Тур	Max	Unit
I <sub>CC</sub>	supply current	on state	36	48	60	mA
		off state	-	2.8	-	mA
G <sub>ass</sub>	associated gain	on state	17	18.3	20	dB
		off state	-	-21	-	dB
NF	noise figure		-	0.43	0.63	dB
P <sub>L(1dB)</sub>	output power at 1 dB gain compression		-	19	-	dBm
IP3 <sub>0</sub>	output third-order intercept point	2-tone; tone spacing = 1 MHz;P <sub>i</sub> = -15 dBm per tone	35	39	-	dBm
		2-tone; tone spacing = 1 MHz; $P_i$ = -15 dBm per <sup>[1]</sup> tone	33	37	-	dBm
RL <sub>in</sub>	input return loss	on state	-	15.9	-	dB
		off state	-	12.5	-	dB
RL <sub>out</sub>	output return loss		-	29	-	dB
ISL	isolation		-	21	-	dB
t <sub>s(pon)</sub>	power-on settling time	$P_i$ = -20 dBm; SHDN (pin 6) from HIGH to LOW <sup>[1]</sup>	-	1.4	-	μs
t <sub>s(poff)</sub>	power-off settling time	$P_i$ = -20 dBm; SHDN (pin 6) from LOW to HIGH <sup>[1]</sup>	-	0.4	-	μs
к	Rollett stability factor	both on state and off state up to f = 20 GHz	1	-	-	
$R_{pd(SHDN)}$	pull-down resistance on pin SHDN		-	10	-	kΩ

[1] For applications where fast switching is required, the value of C1 and C2 should be changed to 100 pF.

#### Table 8. Shutdown control

 $V_{CC} = 5 \text{ V}, T_{amb} = 25 \text{ °C}, \text{ input and output 50 } \Omega; R_{bias} = 5.1 \text{ k}\Omega; \text{ unless otherwise specified. All RF parameters are measured in an application board as shown in Figure 16 with components listed in Table 9 optimized for f = 900 MHz.}$ 

State	V <sub>ctrl(sd)</sub> <sup>[1]</sup>	Unit
on state	≤ 0.6	V
off state	≥ 1.2	V

[1] Voltage on pin 6 (SHDN).

#### aaa-010271 aaa-010272 28 30 G<sub>p</sub> (dB) G<sub>p</sub> (dB) 25 24 20 (1) 3 15 20 (1)10 16 5 0 12 0.3 0.5 0.7 0.9 1.1 1.3 f (GHz) 1.5 0.3 0.5 0.7 0.9 1.1 1.3 f (GHz) 1.5 V<sub>CC</sub>= 5 V; I<sub>CC</sub>= 48 mA. V<sub>CC</sub>= 5 V; T<sub>amb</sub>= 25°C. (1) T<sub>amb</sub>=-40°C (1) I<sub>CC</sub>= 30 mA (2) T<sub>amb</sub>= +25°C (2) I<sub>CC</sub>= 45 mA (3) T<sub>amb</sub>= +85°C (3) I<sub>CC</sub>= 60 mA Figure 3. Power gain as a function of frequency; typical Figure 4. Power gain as a function of frequency; typical values values





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# **BGU8051**

#### Low noise high linearity amplifier





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# **12** Application information



### Table 9. List of components

See Figure 16 for schematics.

Component	Description	Value	Remarks
C1, C2	capacitor	100 nF	
		100 pF	recommended for TDD systems
C3, C5	capacitor	10 pF	
C4	capacitor	10 nF	
L1	inductor	33 nH	
R1	resistor	10 Ω	
R <sub>bias</sub>	resistor	5.1 kΩ	V <sub>CC</sub> = 5 V
		2.3 kΩ	V <sub>CC</sub> = 3.3 V

# **BGU8051**

#### Low noise high linearity amplifier

#### Table 10. Typical performance BGU8051 application board V<sub>CC</sub> = 5 V

All RF parameters are measured at the application board as shown in Figure 16 with the components as listed in Table 9 while optimized for: f = 900 MHz, V<sub>CC</sub> = 5 V, I<sub>CC</sub> = 48 mA and T<sub>amb</sub> = 25 °C. Unless otherwise specified.

Symbol	Parameter	Conditions	f (MHz)						
			400	500	700	750	800	900	1500
G	gain		24.6	23.0	20.4	19.8	19.3	18.3	14.1
RL <sub>in</sub>	input return loss		9.3	11.0	13.7	14.2	14.7	15.9	20.7
RL <sub>out</sub>	output return loss		15.0	18.0	23.5	24.8	26.1	29.0	23.7
P <sub>L(1dB)</sub>	output power at 1 dB gain compression		17.9	18.8	19.8	18.7	19.4	19.4	18.5
IP3 <sub>0</sub>	output third-order intercept point	[1]	35.5	37.9	39.5	39.6	39.8	39.9	39.2
		[1]	35.6	37.2	38.8	39.3	39.1	39.8	38.2
NF	noise figure	[3]	0.41	0.39	0.40	0.39	0.37	0.40	0.43

For 2 Tone: tone spacing = 1MHZ, Po=5 dBm per tone [1]

For applications where fast switching is required, the value of C1 and C2 should be changed to 100 pF.

[2] [3] Connector and board losses not de-embedded.

#### Table 11. Typical performance BGU8051 application board V<sub>CC</sub> = 3.3 V

All RF parameters measured at application board shown in Figure 16. The components listed in Table 9 optimized for 1900 MHz;  $V_{CC} = 3.3 V$ ;  $I_{CC} = 48 mA$ ;  $T_{amb} = 25 °C$ .

Symbol	Parameter	r Conditions f (MHz)							
			400	500	700	750	800	900	1500
G	gain		24.5	22.9	20.4	19.8	19.3	18.2	14.0
RL <sub>in</sub>	input return loss		9.1	10.5	14.1	13.5	14.1	14.3	19.2
RL <sub>out</sub>	output return loss		16.8	18.1	22.3	22.4	24.1	25.0	26.5
P <sub>L(1dB)</sub>	output power at 1 dB gain compression		15.9	16.4	16.6	16.1	16.3	16.3	15.4
IP3 <sub>0</sub>	output third-order intercept point	[1]	32.4	34.3	35.5	34.5	34.1	35.3	31.6
		[1]	32.4	33.1	33.6	33.6	33.1	33.2	30.2
NF	noise figure	[3]	0.39	0.40	0.42	0.43	0.44	0.44	0.43

For 2 Tone: tone spacing = 1MHZ, Po=5 dBm per tone [1]

For applications where fast switching is required, the value of C1 and C2 should be changed to 100 pF.

[2] [3] Connector and board losses not de-embedded.

# 13 Package outline



#### Figure 17. Package outline SOT1327-1 (HWSON8)

# **14 Abbreviations**

Table 12. Abbreviations				
Acronym	Description			
CDMA	Code Division Multiple Access			
ESD	ElectroStatic Discharge			
FDD	Frequency-Division Duplexing			
GSM	Global System for Mobile Communication			
LNA	Low Noise Amplifier			
LTE	Long-Term Evolution			
RF	Radio Frequency			
TDD	Time-Division Duplexing			
W-CDMA	Wideband Code Division Multiple Access			

# 15 Revision history

Table 13. Revision history								
Document ID	Release date	Data sheet status	Change notice	Supersedes				
BGU8051 v.7	20170608	Product data sheet	-	BGU8051 v.6				
Modifications:	<ul> <li><u>Table 4</u>: the maximum value of V<sub>ESD</sub> has been changed into 1.5 kV</li> </ul>							
BGU8051 v.6	20170502	Product data sheet	-	BGU8051 v.5				
Modifications:	<ul> <li><u>Table 5 "Recommended operating conditions"</u>: the minimum value of V<sub>CC</sub> has been changed into 3.3 V</li> </ul>							
BGU8051 v.5	20170120	Product data sheet	-	BGU8051 v.4				
Modifications:	<u>Section 1 "General description"</u> : added BTS1001L according to our new naming convention							
BGU8051 v.4	20160418	Product data sheet	-	BGU8051 v.3				
Modifications:	<ul> <li>3 V to 5 V single supply, added to <u>Section 2 "Features and benefits"</u></li> <li>An additional curve added to <u>Figure "Output power at 1 dB gain compression as a function of supply current; typical values" on page 8</u></li> <li>Added <u>Table 11 "Typical performance BGU8051 application board VCC = 3.3 V" on page 11</u></li> <li>Added <u>Figure 1 "Block diagram" on page 2</u></li> <li>Added remark to R<sub>bias</sub> in <u>Table 9 "List of components"</u></li> </ul>							
BGU8051 v.3	20140929	Product data sheet	-	BGU8051 v.2				
Modifications:	Figure 1 on page 2: figure has been corrected							
BGU8051 v.2	20131230	Product data sheet	-	BGU8051 v.1				
BGU8051 v.1	20131127	Product data sheet	-	-				

## **16 Legal information**

### 16.1 Data sheet status

Document status <sup>[1][2]</sup>	Product status <sup>[3]</sup>	Definition
Objective [short] data sheet	Development	This document contains data from the objective specification for product development.
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# **BGU8051**

#### Low noise high linearity amplifier

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# **BGU8051**

Low noise high linearity amplifier

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